# MHV507-19-1 Si Hyperabrupt Varactor Diode

#### **Datasheet**

#### **Features**

High capacitance ratio: 3.0 Minimum

· High quality factor: 1500 Typical

Compact surface mount package

Ultra-thin termination plating to combat embrittlement

RoHS compliant

#### **Applications**

- Voltage controlled filters
- Analog voltage controlled phase shifters
- · Voltage controlled oscillators

### **Description**

The Aeroflex/Metelics MHV507-19-1 silicon hyperabrupt tuning varactor offers a large change in junction capacitance over a small tuning voltage range. It is a mesa device with an epitaxially-deposited cathode layer for low series resistance and high quality factor. The die is passivated with a high-reliability glass passivation for very fast settling time. The MHV507-19-1 is packaged in an epoxy-encapsulated surface mount package.

The MHV507-19-1 silicon hyperabrupt junction varactor diode complies with the RoHS requirements.

## **Environmental Capabilitites**

The MHV507-19-1 silicon hyperabrupt junction varactor diode is durable and capable of reliably operating in military, commercial, and industrial environments. The device is compatible with pick-and-place assembly and is available in tape and reel. The MHV507-19-1 silicon hyperabrupt junction varactor diode is capable of meeting the environmental requirements of MIL-STD-750

### **ESD** and Moisture Sensitivity Level Rating

As are all semiconductors, silicon hyperabrupt tuning varactor diode are susceptible to damage from ESD events. Proper ESD prevention procedures should be followed. The ESD rating for this device is Class 0 (HBM). The moisture sensitivity level (MSL) rating for this part is MSL 1.



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## **Electrical Specifications**

 $T_A = 25^{\circ}C$  (Unless Otherwise Noted)

Parameter	Symbol	Test Conditions	Minimum Value	Typical Value	Maximum Value	Units
Breakdown Voltage	V <sub>B</sub>	$I_{_{R}}=10~\mu A$	22			V
Reverse Leakage Current	<b> </b>	$V_{_{R}} = 20 \text{ V}$			50	nA
Total Capacitance	C <sub>T</sub>	f = 1 MHz				
		$V_{R} = 0 V$	9.2	10.2	11.2	pF
		$V_{R} = 4 V$	3.2	3.5	3.8	pF
		$V_R = 20 V_r$	0.75	1.0	1.4	pF
Capacitance Ratio		$V_R = 4 \text{ V to } V_R = 20 \text{ V},$ $f = 1 \text{MHz}$	3.0		5.5	
Quality Factor	$Q_4$	$V_{_{R}} = 4.0 \text{ V, f} = 50 \text{ MHz}$		1500		

## **Absolute Maximum Ratings**

 $T_{\text{\tiny CASE}} = +25^{\circ}\text{C}$  (Unless Otherwise Noted)

Parameter	Conditions	Absolute Maximum Value
Operating Temperature		- 55 °C to 85 °C
Storage Temperature		- 55 °C to 100 °C
Assembly Temperature	t = 10 s	260 °C
Forward DC Current		50 mA
Reverse DC Voltage		22 V

## MHV507-19-1 Si Hyperabrupt Varactor Diode



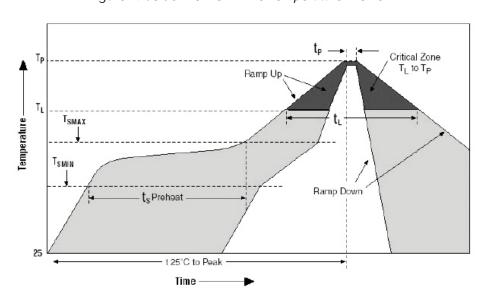
#### **Assembly Instructions**

Diodes may be placed onto circuit boards with pick and place manufacturing equipment from tape-reel. The devices are attached to the circuit using conventional solder re-flow or wave soldering procedures with RoHS type or Sn 60 / Pb 40 type solders.

Table 1. Time-Temperature Profile for Sn60/Pb40 or RoHS Type Solders

Profile Feature	SnPb Solder Assembly	Pb-Free Solder Assembly	
Average Ramp-Up Rate (T <sub>L</sub> to T <sub>P</sub> )	3°C /second maximum	3°C /second maximum	
Preheat:			
- Temperature Min (T <sub>smin</sub> )	100°C	150°C	
- Temperature Max (T <sub>smax</sub> )	150°C	200°C	
- Time (min to max)(t <sub>s</sub> )	60-120 s	60-180 s	
T <sub>SMAX</sub> to T <sub>L</sub> - Ramp-Up Rate		3°C/s maximum	
Time Maintained Above: - Temperature (T <sub>L</sub> ) - Time (t <sub>L</sub> )	<mark>183</mark> °C 60-150 s	217°C 60-150 s	
Peak temperature (T <sub>P</sub> )	225 +0/-5°C	260 +0/-5°C	
Time Within 5°C of Actual Peak Temperature (t <sub>p</sub> )	10 – 30 s	20 – 40 s	
Ramp-Down Rate	6°C /s maximum	6°C /s maximum	
Time 25°C to Peak Temperature	6 minutes maximum	8 minutes maximum	

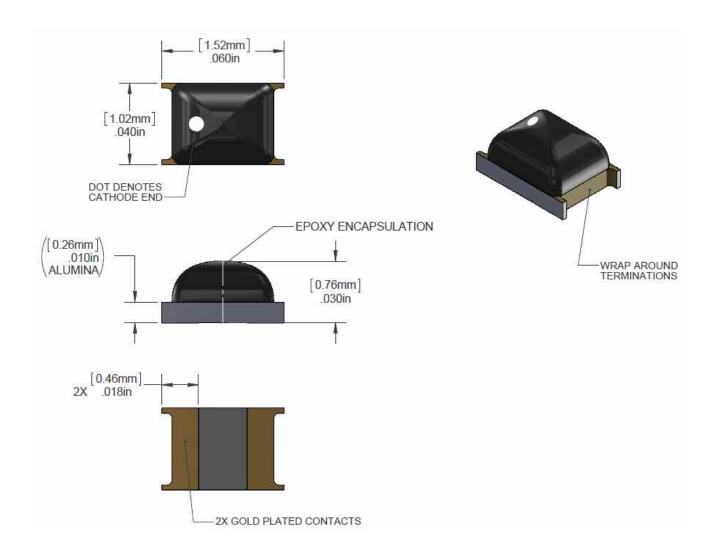
Figure 1. Solder Re-Flow Time-Temperature Profile



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## **Outline - Case Style CS19-1**



#### Notes:

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- 1. All dimensions in inches [mm].
- 2. Ceramic carrier is alumina (Al<sub>2</sub>O<sub>2</sub>).
- 3. Metal terminals composed of electrolytic Au over electrolytic Ni.





#### **Part Number Ordering Information**

Part Number	Description	
MHV507-19-1-W	Waffle Pack (Quantity = 100 per pack)	
MHV507-19-1-R	Tape-Reel Packaging (Quantity = 3000 Maximum)	

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